

| | Type | L # | Hits | Search Text | DBs |
|---|------|-----|------|--|---|
| 1 | BRS | L1 | 7875 | bpsg same (oxide or "silicon oxide" or SiO or "SiO.sub.2") | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB |
| 2 | BRS | L2 | 4572 | ("silicon nitride" or SiN or "Si.sub.3N.sub.4") and 1 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB |
| 3 | BRS | L3 | 1509 | @ad<=19970204 and 2 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB |
| 4 | BRS | L4 | 1450 | semiconductor and 3 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB |
| 5 | BRS | L5 | 1422 | substrate and 4 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB |
| 6 | BRS | L6 | 578 | capacitor and 5 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB |